

Figure 1 Low room-temperature resistivity for 26 – 55 nm $\text{Nb}_x\text{Ti}_{1-x}\text{N}$ films prepared with varying $\text{Nb}/(\text{Nb}+\text{Ti})$ cycle ratio. The approximately linear rise of resistivity with Nb content suggests good mixing of the $\text{Nb}_x\text{Ti}_{1-x}\text{N}$ constituents.

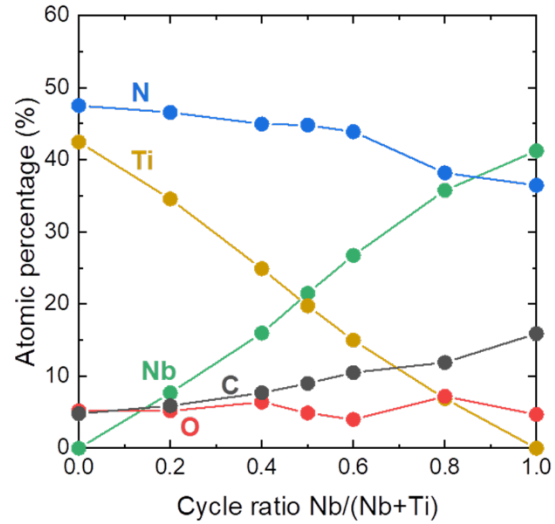


Figure 2 $\text{Nb}_x\text{Ti}_{1-x}\text{N}$ bulk composition measured by XPS for films prepared with varying $\text{Nb}/(\text{Nb}+\text{Ti})$ cycle ratio demonstrating accurate composition control.

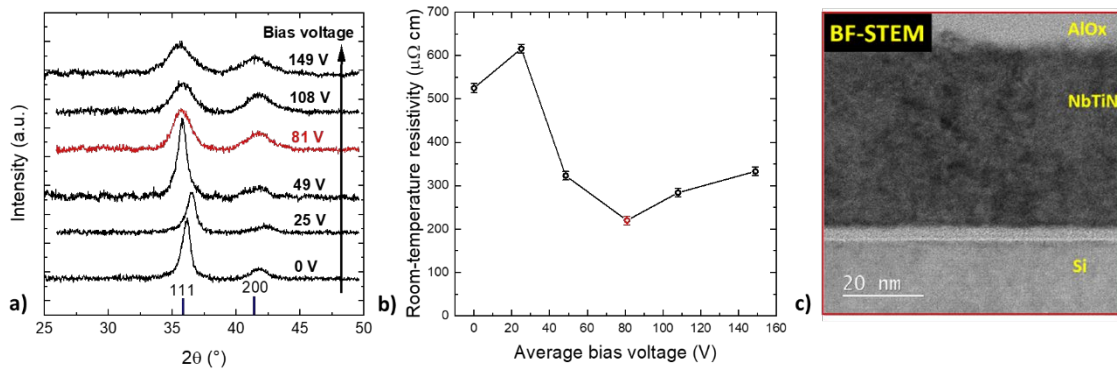


Figure 3 Influence of substrate bias voltage on crystallinity and conductivity. **a)** X-ray diffractograms and **b)** room-temperature resistivity of 28 – 35 nm $\text{Nb}_{0.5}\text{Ti}_{0.5}\text{N}$ films prepared with $\text{Nb}/(\text{Nb}+\text{Ti}) = 0.5$ cycle ratio and varying bias voltage. **c)** BF-STEM image of a cross-section of a 49 nm $\text{Nb}_{0.5}\text{Ti}_{0.5}\text{N}$ film prepared with $\text{Nb}/(\text{Nb}+\text{Ti}) = 0.5$ cycle ratio and 90 V bias. The similar settings amongst the three images are indicated in red.